

# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V <sub>BE</sub> = 0V)	V <sub>CES</sub>	700	V
Collector-Emitter Voltage	V <sub>CEO</sub>	450	V
Emitter-Base Voltage	V <sub>EBO</sub>	9	V
Continuous Collector Current	Ι <sub>C</sub>	1.5	А
Peak Pulse Collector Current (Note 5)	I <sub>CM</sub>	3	А
Continuous Base Current	IB	0.75	А
Peak Pulse Base Current (Note 5)	I <sub>BM</sub>	1.5	А

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)		3.9		
	(Note 7)	- PD -	2.5	W	
	(Note 8)		2.1		
	(Note 9)		1.6		
Thermal Resistance, Junction to Ambient Air	(Note 6)		32		
	(Note 7)	R <sub>0JA</sub>	51	°C/W	
	(Note 8)		59		
	(Note 9)	-	80		
Thermal Resistance, Junction to Leads	(Note 10)	R <sub>θJL</sub>	3		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

#### ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

 5. Pulse test for pulse width < 5ms, duty cycle ≤ 10%.</li>
6. For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Same as note (6), except the device is surface mounted on 25mm x 25mm 2oz copper.

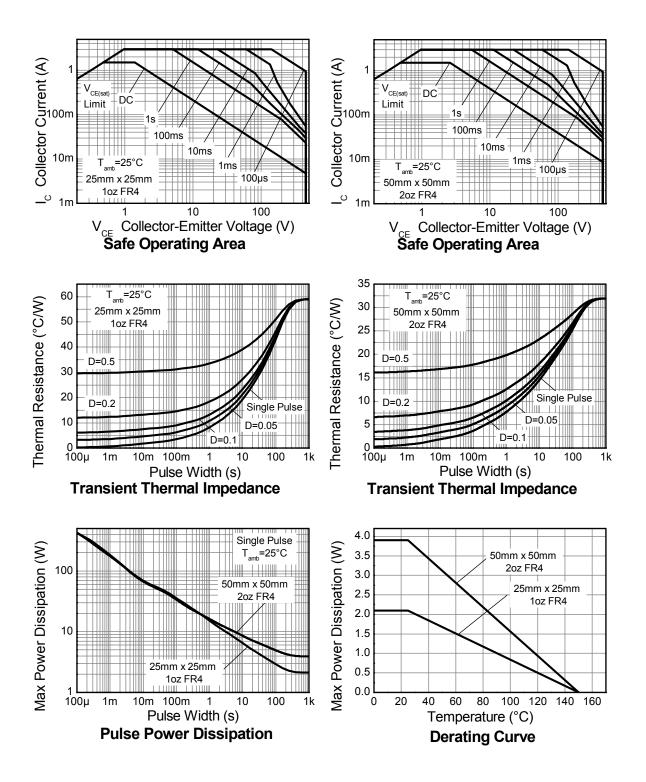
8. Same as note (6), except the device is surface mounted on 25mm x 25mm 1oz copper.

9. Same as note (6), except mounted on minimum recommended pad (MRP) layout.

Thermal resistance from junction to solder-point (on the exposed collector pad).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



### Thermal Characteristics and Derating Information



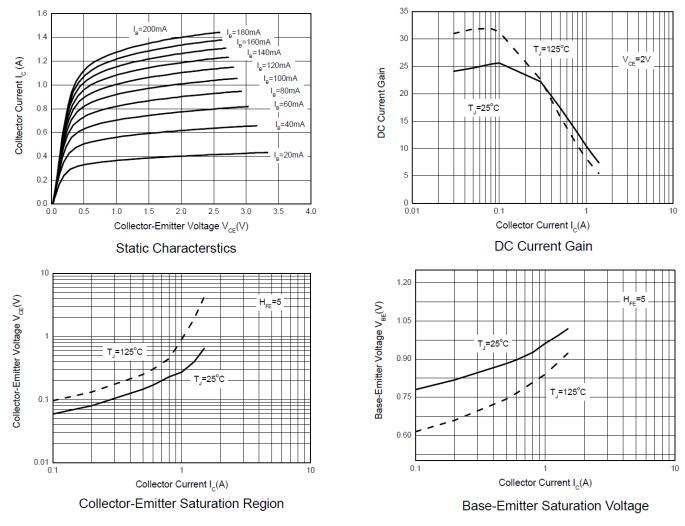


# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	_	—	V	I <sub>C</sub> = 100μA, V <sub>BE</sub> = 0V
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	450	—	—	V	I <sub>C</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	9	—	—	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	ICEV	_	—	10	μA	V <sub>CE</sub> = 700V, V <sub>BE</sub> = -1.5V
DC current transfer Static ratio (Note 12)	h <sub>FE</sub>	20 16 5	<b>—</b> —	40 30 25		$\begin{split} I_{C} &= 20 \text{mA},  V_{CE} = 10 \text{V} \\ I_{C} &= 0.5 \text{A},  V_{CE} = 2 \text{V} \\ I_{C} &= 1.0 \text{A},  V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 12)	V <sub>CE(sat)</sub>		_	0.3 0.4	V	I <sub>C</sub> = 0.5A, I <sub>B</sub> = 0.1A I <sub>C</sub> = 1A, I <sub>B</sub> = 0.25A
Base-Emitter Saturation Voltage (Note 12)	V <sub>BE(sat)</sub>		—	1.0 1.2	V	I <sub>C</sub> = 0.5A, I <sub>B</sub> = 0.1A I <sub>C</sub> = 1A, I <sub>B</sub> = 0.25A
Output Capacitance	C <sub>ob</sub>	_	18	—	pF	V <sub>CB</sub> = 10V, f = 0.1MHz
Transition Frequency	f <sub>T</sub>	4	_	—	MHz	I <sub>C</sub> = 0.1A, V <sub>CE</sub> = 10V
Turn-on Time with Resistive Load	t <sub>on</sub>	_	0.35			
Storage Time with Resistive Load	ts	—	2.31	_	μs	I <sub>C</sub> = 1A,V <sub>CC</sub> = 125V, I <sub>B1</sub> = 0.2A, I <sub>B2</sub> = -0.2A
Fall Time with Resistive Load	t <sub>f</sub>	_	0.21	—		IB50.52

Note: 12. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.

#### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

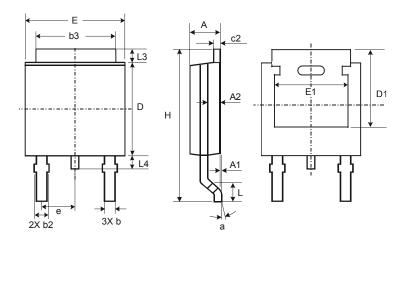


DXT13003DK Datasheet Number: DS37297 Rev. 1 - 2 Downloaded from Arrow.com.



### **Package Outline Dimensions**

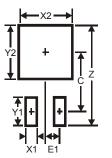
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	_	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All D	All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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